# **BLF881; BLF881S**

# UHF power LDMOS transistor Rev. 4 — 1 September 2015

**AMMPLEON** 

Product data sheet

#### **Product profile** 1.

#### 1.1 General description

A 140 W LDMOS RF power transistor for broadcast transmitter applications and industrial applications. The transistor can deliver 140 W from HF to 1 GHz. The excellent ruggedness and broadband performance of this device makes it ideal for digital transmitter applications.

Typical performance Table 1.

RF performance at V<sub>DS</sub> = 50 V in a common-source 860 MHz test circuit.

Mode of operation	f (MHz)		P <sub>L(PEP)</sub> (W)	P <sub>L(AV)</sub> (W)			IMD3 (dBc)	
2-tone, class AB	f <sub>1</sub> = 860; f <sub>2</sub> = 860.1	` '	` '	-		49		-
DVB-T (8k OFDM)	858	-	-	33	21	34	-	-33 <mark>[1]</mark>

<sup>[1]</sup> Measured [dBc] with delta marker at 4.3 MHz from center frequency.

#### **CAUTION**



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

#### 1.2 Features and benefits

- 2-Tone performance at 860 MHz, a drain-source voltage V<sub>DS</sub> of 50 V and a quiescent drain current  $I_{Da} = 0.5 A$ :
  - ◆ Peak envelope power load power = 140 W
  - Power gain = 21 dB
  - ◆ Drain efficiency = 49 %
  - ◆ Third order intermodulation distortion = -34 dBc
- DVB performance at 858 MHz, a drain-source voltage V<sub>DS</sub> of 50 V and a quiescent drain current  $I_{Dq} = 0.5 A$ :
  - ◆ Average output power = 33 W
  - Power gain = 21 dB
  - ◆ Drain efficiency = 34 %
  - ◆ Shoulder distance = -33 dBc (4.3 MHz from center frequency)
- Integrated ESD protection
- Excellent ruggedness
- High power gain

- High efficiency
- Excellent reliability
- Easy power control
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

## 1.3 Applications

- Communication transmitter applications in the UHF band
- Industrial applications in the UHF band

## 2. Pinning information

Table 2. Pinning

Table 2.	Pinning			
Pin	Description		Simplified outline	Graphic symbol
BLF881 (	SOT467C)			
1	drain			
2	gate			1 
3	source	<u>[1]</u>		2
				3 sym112
				3ym112
BLF881S	(SOT467B)			
1	drain			,
2	gate			1 
3	source	<u>[1]</u>	-3	2
				3
				sym112

<sup>[1]</sup> Connected to flange.

## 3. Ordering information

Table 3. Ordering information

Type number	Packa	ackage					
	Name	Description	Version				
BLF881	-	flanged LDMOST ceramic package; 2 mounting holes; 2 leads	SOT467C				
BLF881S	_	earless LDMOST ceramic package; 2 leads	SOT467B				

## 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage		-	104	V
$V_{GS}$	gate-source voltage		-0.5	+13	V
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	200	°C

## 5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions		Тур	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	$T_{case} = 80  ^{\circ}C;$ $P_{L(AV)} = 70  W$	[1]	0.95	K/W

<sup>[1]</sup>  $R_{th(j-c)}$  is measured under RF conditions.

## 6. Characteristics

Table 6. DC characteristics

 $T_i = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 1.35 \text{ mA}$	[1]	104	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	V <sub>DS</sub> = 10 V; I <sub>D</sub> = 135 mA	[1]	1.4	-	2.4	V
I <sub>DSS</sub>	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}$		-	-	1.4	μΑ
I <sub>DSX</sub>	drain cut-off current	$V_{GS} = V_{GSth} + 3.75 \text{ V}; V_{DS} = 10 \text{ V}$		19	21	-	Α
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 10 V; V <sub>DS</sub> = 0 V		-	-	140	nA
R <sub>DS(on)</sub>	drain-source on-state resistance	$V_{GS} = V_{GSth} + 3.75 \text{ V}; I_D = 4.5 \text{ A}$	[1]	-	210	-	$m\Omega$
C <sub>iss</sub>	input capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}$		-	100	-	pF
Coss	output capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}$		-	33.5	-	pF
C <sub>rss</sub>	reverse transfer capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}$		-	1	-	pF

<sup>[1]</sup>  $I_D$  is the drain current.

Table 7. RF characteristics

 $T_h = 25$  °C unless otherwise specified.

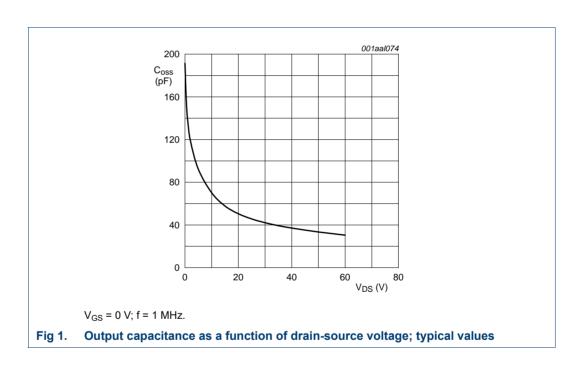
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
2-Tone, cla	ss AB					
$V_{DS}$	drain-source voltage		-	50	-	V
$I_{Dq}$	quiescent drain current		-	0.5	-	Α
P <sub>L(PEP)</sub>	peak envelope power load	d power	-	140	-	W
Gp	power gain		20	21	-	dB
$\eta_{D}$	drain efficiency		45	49	-	%
IMD3	third-order intermodulation	n distortion	-	-34	-30	dBc
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Table 7. RF characteristics ...continued

 $T_h = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
DVB-T (8k	(OFDM)					
$V_{DS}$	drain-source voltage		-	50	-	V
I <sub>Dq</sub>	quiescent drain current		-	0.5	-	Α
$P_{L(AV)}$	average output power		-	33	-	W
Gp	power gain		20	21	-	dB
η <sub>D</sub>	drain efficiency		30	34	-	%
IMD <sub>shldr</sub>	intermodulation distortion shoulder		<u>[1]</u> _	-33	-30	dBc
PAR	peak-to-average ratio		[2] _	8.3	-	dB

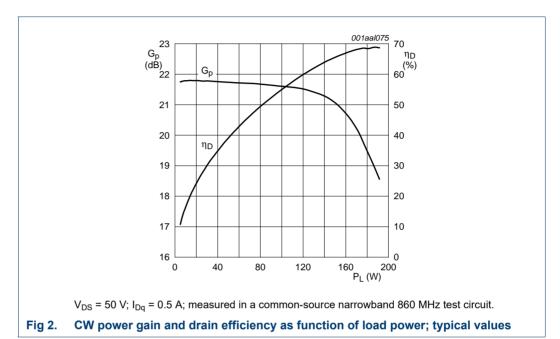
- [1] Measured [dBc] with delta marker at 4.3 MHz from center frequency.
- [2] PAR (of output signal) at 0.01 % probability on CCDF; PAR of input signal = 9.5 dB at 0.01 % probability on CCDF.



## 7. Application information

## 7.1 Narrowband RF figures

#### 7.1.1 CW



#### 7.1.2 2-Tone

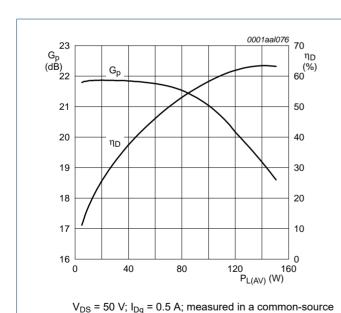
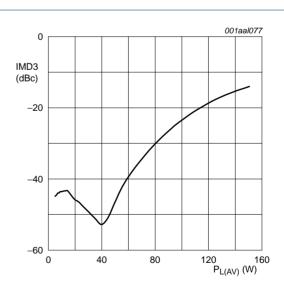


Fig 3. 2-Tone power gain and drain efficiency as function of average load power; typical values

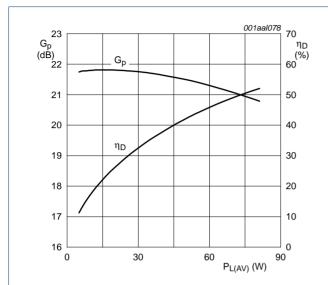
narrowband 860 MHz test circuit.



 $V_{DS}$  = 50 V;  $I_{Dq}$  = 0.5 A; measured in a common-source narrowband 860 MHz test circuit.

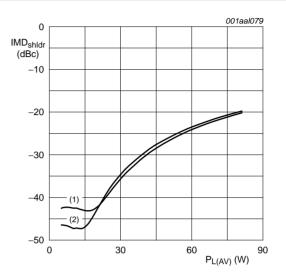
Fig 4. 2-Tone third order intermodulation distortion as a function of average load power; typical values

#### 7.1.3 **DVB-T**



 $V_{DS}$  = 50 V;  $I_{Dq}$  = 0.5 A; measured in a common-source narrowband 860 MHz test circuit.

Fig 5. DVB-T power gain and drain efficiency as function of average load power; typical values



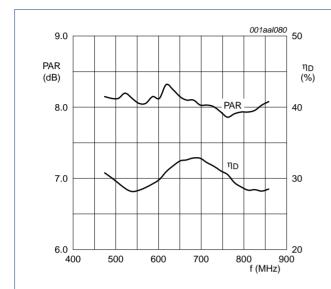
 $V_{DS}$  = 50 V;  $I_{Dq}$  = 0.5 A; measured in a common-source narrowband 860 MHz test circuit.

- (1) Lower adjacent channel
- (2) Upper adjacent channel

Fig 6. DVB-T shoulder distance as a function of average load power; typical values

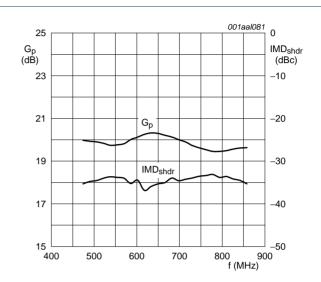
## 7.2 Broadband RF figures

#### 7.2.1 DVB-T



 $V_{DS}$  = 50 V;  $I_{Dq}$  = 0.35 A;  $P_{L(AV)}$  = 33 W; measured in a common-source broadband test circuit as described in Section 8.

Fig 7. DVB-T PAR at 0.01 % probability on the CCDF and drain efficiency as function of frequency; typical values



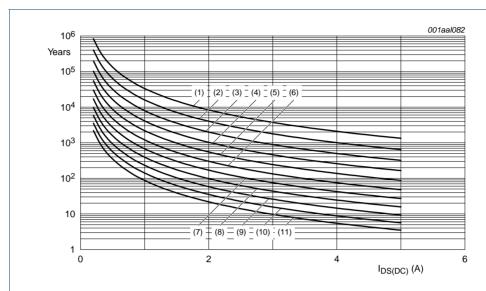
 $V_{DS}$  = 50 V;  $I_{Dq}$  = 0.35 A;  $P_{L(AV)}$  = 33 W; measured in a common-source broadband test circuit as described in Section 8.

Fig 8. DVB-T power gain and shoulder distance as function of frequency; typical values

#### 7.3 Ruggedness in class-AB operation

The BLF881 and BLF881S are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions:  $V_{DS}$  = 50 V; f = 860 MHz at rated power. Ruggedness is measured in the application circuit as described in Section 8.

## 7.4 Reliability



TTF (0.1 % failure fraction).

The reliability at pulsed conditions can be calculated as follows: TTF (0.1 %)  $\times$  1 /  $\delta$ .

- (1)  $T_i = 100 \, ^{\circ}C$
- (2)  $T_i = 110 \, ^{\circ}C$
- (3)  $T_i = 120 \, ^{\circ}C$
- (4)  $T_i = 130 \, ^{\circ}C$
- (5)  $T_i = 140 \, ^{\circ}C$
- (6)  $T_i = 150 \, ^{\circ}\text{C}$
- (7)  $T_i = 160 \, ^{\circ}C$ (8)  $T_i = 170 \, ^{\circ}\text{C}$
- (9)  $T_j = 180 \, ^{\circ}C$
- (10)  $T_i = 190 \, ^{\circ}C$
- (11)  $T_i = 200 \, ^{\circ}C$

**BLF881** electromigration

## 8. Test information

Table 8. List of components

For test circuit, see Figure 10, Figure 11 and Figure 12.

Component	Description	Value		Remarks
C1, C2	multilayer ceramic chip capacitor	5.1 pF	[1]	
C3, C4	multilayer ceramic chip capacitor	10 pF	[2]	
C5	multilayer ceramic chip capacitor	6.8 pF	<u>[1]</u>	
C6	multilayer ceramic chip capacitor	4.7 pF	<u>[1]</u>	
C7	multilayer ceramic chip capacitor	2.7 pF	<u>[1]</u>	
C8, C9, C10, C25, C26	multilayer ceramic chip capacitor	100 pF	[1]	
C11, C27	multilayer ceramic chip capacitor	10 μF		TDK C570X7R1H106KT000N or capacitor of same quality.
C12	electrolytic capacitor	470 μF; 63 V		
C20	multilayer ceramic chip capacitor	10 pF	[3]	
C21	multilayer ceramic chip capacitor	8.2 pF	[3]	
C22	trimmer	0.6 pF to 4.5 pF		Tekelec
C23	multilayer ceramic chip capacitor	6.8 pF	[3]	
C24	multilayer ceramic chip capacitor	3.9 pF	[3]	
L1	stripline	-	[4]	(W $\times$ L) 7 mm $\times$ 15 mm
L2	stripline	-	[4]	(W $\times$ L) 2.4 mm $\times$ 9 mm
L3	stripline	-	[4]	(W × L) 2.4 mm × 10 mm
L4	stripline	-	[4]	(W $\times$ L) 2.4 mm $\times$ 25 mm
L5	stripline	-	[4]	(W × L) 2.4 mm × 10 mm
L6	stripline	-	[4]	(W × L) 2.0 mm × 20 mm
L7	stripline	-	[4]	(W $\times$ L) 2.0 mm $\times$ 21 mm
L20	stripline	-	[4]	(W $\times$ L) 7 mm $\times$ 12 mm
L21	stripline	-	<u>[4]</u>	(W $\times$ L) 2.4 mm $\times$ 13 mm
L22	stripline	-	[4]	(W $\times$ L) 2.4 mm $\times$ 31 mm
L23	stripline	-	[4]	(W $\times$ L) 2.4 mm $\times$ 5 mm
R1	resistor	100 Ω		
R2	resistor	10 kΩ		

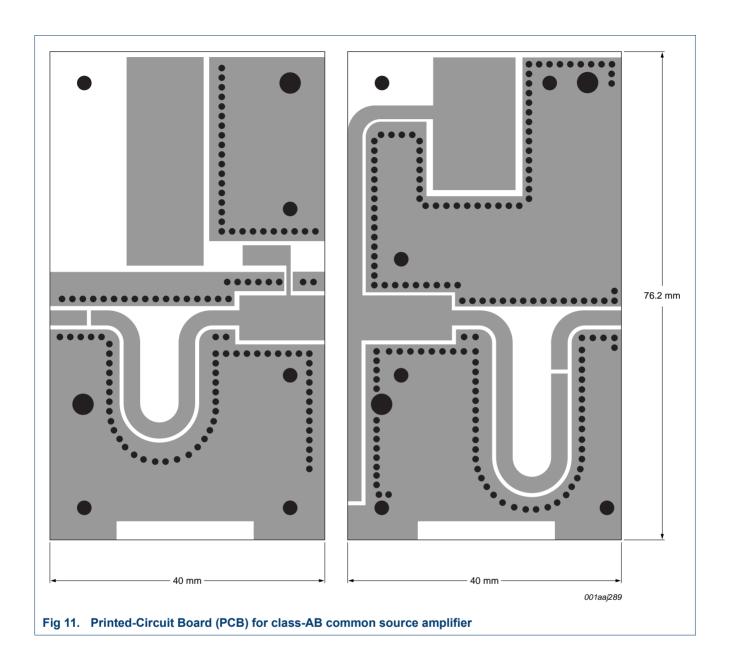
<sup>[1]</sup> American technical ceramics type 100B or capacitor of same quality.

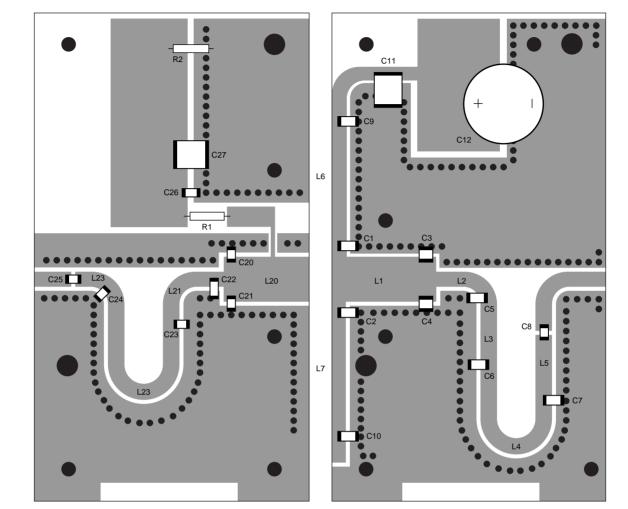
<sup>[2]</sup> American technical ceramics type 180R or capacitor of same quality.

<sup>[3]</sup> American technical ceramics type 100A or capacitor of same quality.

<sup>[4]</sup> Printed-Circuit Board (PCB): Rogers 5880;  $\varepsilon_r$  = 2.2 F/m; height = 0.79 mm; Cu (top/bottom metallization); thickness copper plating = 35  $\mu$ m.

Product data sheet BLF881\_BLF881S#4 C27 · V<sub>DD</sub> All information provided in this document is subject to legal disclaimers C26 Rev. 4 — 1 September 2015 C20 C25 L21 L1 L22 L20 L2 L4 L3 -||-|C2 **‡** C24 C22 C21 **=** C5 HL7 001aaj288 © Ampleon The Netherlands B.V. 2015. All rights reserved. 10 of 18 See Table 8 for a list of components. Fig 10. Class-AB common-source broadband amplifier





001aaj290

See <u>Table 8</u> for a list of components.

Fig 12. Component layout for class-AB common source amplifier

## 9. Package outline

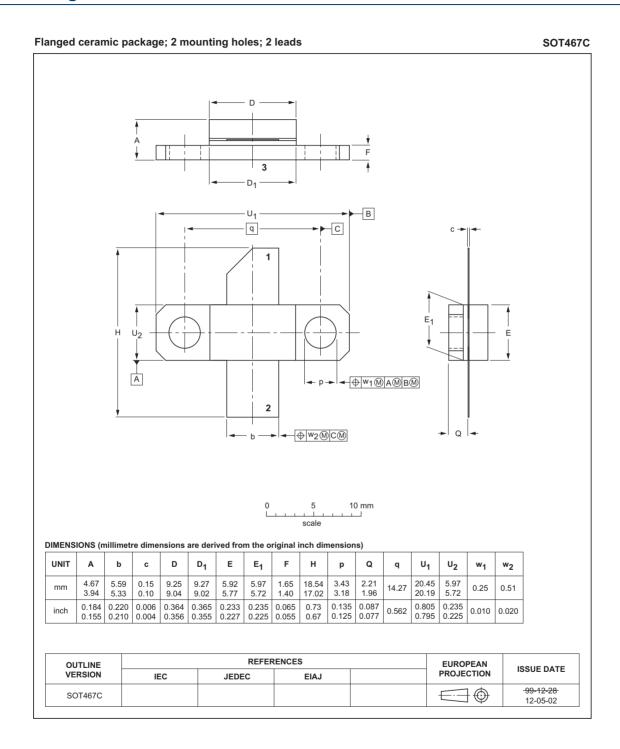


Fig 13. Package outline SOT467C

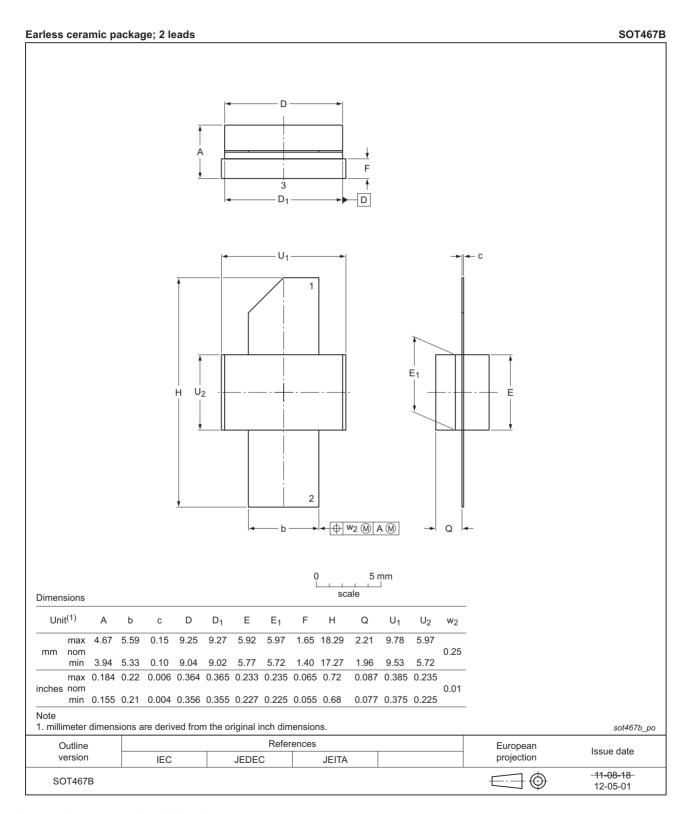


Fig 14. Package outline SOT467B

## 10. Abbreviations

Table 9. Abbreviations

Acronym	Description
CW	Continuous Wave
CCDF	Complementary Cumulative Distribution Function
DVB	Digital Video Broadcast
DVB-T	Digital Video Broadcast - Terrestrial
ESD	ElectroStatic Discharge
HF	High Frequency
IMD3	Third order InterModulation Distortion
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
LDMOST	Laterally Diffused Metal-Oxide Semiconductor Transistor
OFDM	Orthogonal Frequency Division Multiplexing
PAR	Peak-to-Average power Ratio
PEP	Peak Envelope Power
RF	Radio Frequency
TTF	Time To Failure
UHF	Ultra High Frequency
VSWR	Voltage Standing-Wave Ratio

## 11. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BLF881_BLF881S#4	20150901	Product data sheet	-	BLF881_BLF881S v.3	
Modifications:	<ul> <li>The format of this document has been redesigned to comply with the new identity guidelines of Ampleon.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>				
BLF881_BLF881S v.3	20101207	Product data sheet	-	BLF881_BLF881S v.2	
BLF881_BLF881S v.2	20100210	Product data sheet	-	BLF881_BLF881S v.1	
BLF881_BLF881S v.1	20091210	Preliminary data sheet	-	-	

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#### 12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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## **BLF881; BLF881S**

## UHF power LDMOS transistor

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